	Sea	t No.: Enrolment No								
		GUJ	ARAT	TEC	CHNO	LOGI	CAL UN	IVERSITY		
								VINTER 2012		
	Sul	bject code: 7130						Date: 10/01/2013		
		bject Name: Na		ces Fa	ahricat	ion Tec	hnology			
		ne: 02.30 pm – 0			abi icae		mology	Total Marks: 70		
		-	03.00 pi	11		Total Walks. 70				
	ins	structions:								
		1. Attempt all	-							
		2. Make suita		_			essary.			
		3. Figures to	me rigiii	muica	ite full III	iarks.				
Q.1	(a)	(a) What are the types of Physical Vapor Deposition? Discuss Sputtering.								
~ ·-	(b)									
	` '			Ü					07	
Q.2	(a)									
	(b)									
		Etching purpose.		10.5	1.0	120	T 4.0	٦		
		C _{AO} mol HBr/lit -r _{AO} X 10 ²	0.0	0.5	1.0	2.0 4.86	12.84	_		
		molHBr/m ² Hr	0.073	0.7	1.04	4.60	12.04			
			reaction r	ate and	Order of	reaction a	assuming 1 m	ole of oxide consumes 4		
		mole of HydroBromic acid. Determine Etching rate in nm/min.								
		M.W. $Mn = 55 O_2 = 32 H_2 = 2 Br_2 = 160$								
	(1)	OR								
	(b)	What is Zone refining? How and Why it is performed?								
Q.3	(a)	What is Epitaxy? Discuss the mechanism of formation of Epitaxial film with reference to								
Ų.S	(a)	What is Epitaxy? Discuss the mechanism of formation of Epitaxial film with reference to making of Silicon epitaxial film over Silicon Substrate.								
	(b)	Discuss construction and working of Reactors used for Chemical Vapor Deposition. 07								
		OR								
Q.3	(a)									
		flats for P ⁺ type and n ⁺ type junctions.								
	(b)	What are Effects of Defects on Crystal in relation to suitability of Crystal for Electronic 07								
		devices? Discuss.								
α	(a)	Discuss Optical Pro	viaction lit	hogrank	287				07	
Q.4	(a) (b)	Discuss Optical Projection lithography. O' Discuss Electron beam Lithography. O' O' O' O' O' O' O' O' O' O								
	(D)	Discuss Election	ocam Liu	iograpi	ıy.	OR			U/	
Q.4	(a)	What are the desired properties of Metal for Metallization? Discuss problems associated 07								
~ ··	(4)	with metallization.								
	(b)	Discus with diagram the Ion Implantation Equipment 07								
Q.5	(a)	Discuss Pre-Oxidative cleaning. 07								
	(b)	Discuss various Oxidation process. Discuss dry and Wet Oxidation process.								
		OR								
Q.5	(a)									
	(b)	Gas Chromatogra	phy as an	analyt	ical tool	in Nano	technology.		07	
